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Hyperfast Rectifier, 75 A FRED Pt[®] G5



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTI	ERISTICS
I _{F(AV)}	75 A
V _R	600 V
V _F at I _F at 125 °C	1.2 V
t _{rr} (typ.)	32
I _{FSM}	615
T _J max.	175 °C
Package	TO-247AD 2L
Circuit configuration	Single

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature FREE
- Polyimide passivation
- AEC-Q101 qualified meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV on-board battery chargers

MECHANICAL DATA

Case: TO-247AD 2L

Molding compound meets UL 94 V-0 flammability rating **Terminal:** matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Repetitive peak reverse voltage	V _{RRM}		600	V						
Average rectified forward current	I _{F(AV)}	T _C = 113 °C, D = 0.50	75							
Non-repetitive peak surge current	I _{FSM}	T_{C} = 25 °C, t_{p} = 10 ms, sine wave	615	A						
Repetitive peak forward current	I _{FRM}	T _C = 113 °C, D = 0.50, f = 20 kHz	150							
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C						

ELECTRICAL SPECIFICATIONS (T_J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-					
Forward voltage	V	I _F = 75 A	-	1.3	1.7	V				
	V _F	I _F = 75 A, T _J = 125 °C	-	1.2	-					
Reverse leakage current	I _R	$V_{R} = V_{R}$ rated	-	-	25					
neverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA				
Junction capacitance	CT	V _R = 200 V	-	96	-	pF				
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH				

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Pb-free RoHS COMPLIANT HALOGEN



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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)											
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS				
		I _F = 1.0 A, dI _F /dt =	100 A/ μ s, V _R = 30 V	-	32	-					
Reverse recovery time	t _{rr}	T _J = 25 °C		-	52	-	ns				
		T _J = 125 °C		-	82	-					
Peak recovery current	I	$T_J = 25 \ ^{\circ}C$	I _F = 50 A dI _F /dt = 1000 A/µs	-	24	-	A				
Feat recovery current	I _{RRM}	T _J = 125 °C	$V_{\rm R} = 400 \text{ V}$	-	51	-					
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	805	-	nC				
neverse recovery charge	Qrr	T _J = 125 °C		-	2515	-					
Reverse recovery time	+	T _J = 25 °C		-	57	-	ns				
neverse recovery time	t _{rr}	T _J = 125 °C		-	90	-					
Pool rocovery ourrent		T _J = 25 °C	I _F = 75 A dI _F /dt = 1000 A/µs	-	28	-	А				
Peak recovery current	I _{RRM}	T _J = 125 °C	$V_{\rm B} = 400 \text{V}$	-	58	-	A				
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	969	-	nC				
neverse recovery charge	Qrr	T _J = 125 °C		-	3090	-	no				

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Thermal resistance, junction-to-case	R _{thJC}		-	-	0.5	°C/W				
Weight			-	5.5	-	g				
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)				
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C				
Marking device		Case style TO-247AD 2L	E5PH7506LH							

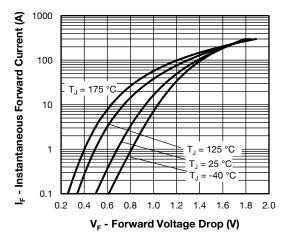


Fig. 1 - Forward Voltage Drop Characteristics

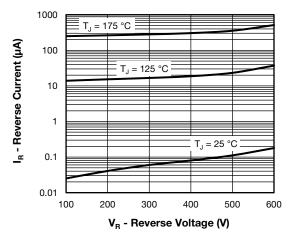
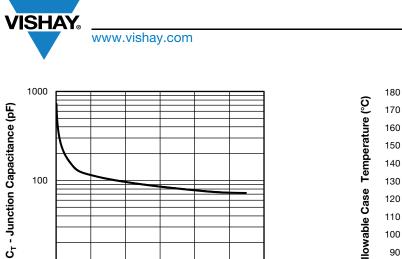


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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V_R - Reverse Voltage (V) Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

300

400

500

600

200

100

10

0

100

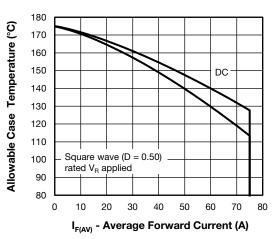


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

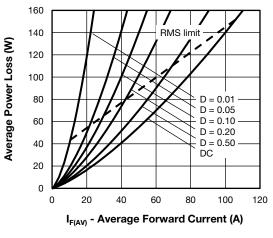


Fig. 5 - Forward Power Loss Characteristics

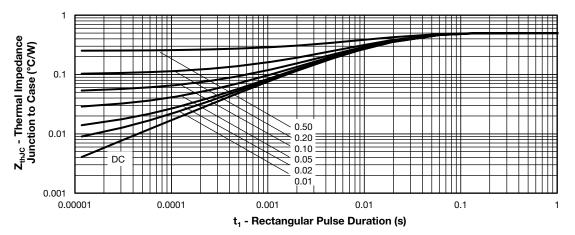


Fig. 6 - Transient Thermal Impedance, Junction to Case

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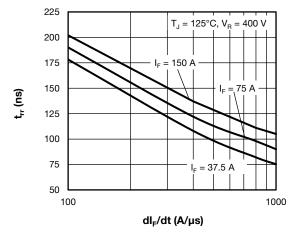


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

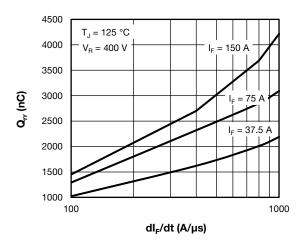


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt

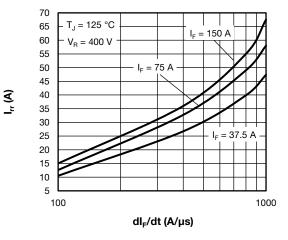


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt

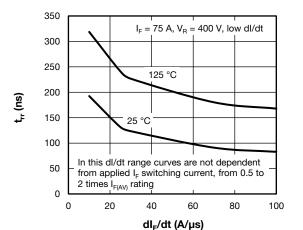
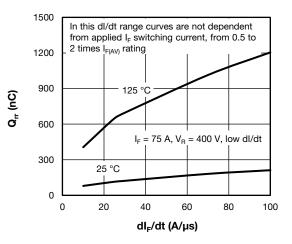


Fig. 10 - Typical Reverse Recovery Time vs. dI_F/dt





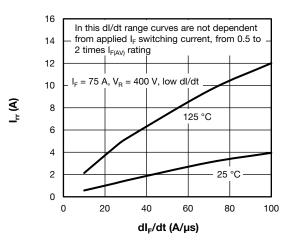


Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt

VS-E5PH7506LHN3

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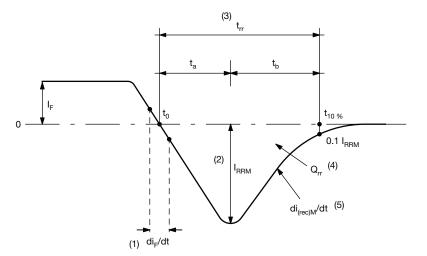


Fig. 13 - Reverse Recovery Waveform and Definitions

Notes

- $^{(1)}~di_{F}/dt$ rate of change of current through zero crossing
- $^{(2)}\ \ I_{RRM}$ peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM}
- $^{(4)}~~\text{Q}_{rr}$ area under curve defined by t_0 and $t_{10}~\%$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t)dt$$

 $^{(5)}~di_{(rec)}M/dt$ - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE

Device code	VS-	E	5	Р	н	75	06	L	н	N3
	1	2	3	4	5	6	7	8	9	10
	1 -	Visł	nay Sem	niconduo	ctors pro	oduct				
	2 - Circuit configuration E = single diode									
	3 -		ED Pt [®] (
	4 -	P =	TO-247	' packag	je					
	5 -	5 - Process type: H = hyperfast recovery								
	6 -	Cur	rent rati	ng (75 =	= 75 A)					
	7 - Voltage rating (06 = 600 V)									
	8 - Package: L = long lead (TO-247AD)									
	9 - H = AEC-Q101 qualified									
	10 -			ntal digit en-free,		complia	nt, and	totally l	ead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-E5PH7506LHN3	25	500	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95536
Part marking information	www.vishay.com/doc?95648
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TO-247AD 2L

DIMENSIONS in millimeters and inches



Section C - C, D - D

(b, b2)

(4)

View	<u>/ B</u>

SYMBOL	MILLIN	MILLIMETERS INCHES		NOTES SYMBOL	MILLIMETERS		INCHES		NOTES		
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	STMDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209		E	15.29	15.87	0.602	0.625	3
A1	2.21	2.59	0.087	0.102		E1	13.46	-	0.53	-	
A2	1.50	2.49	0.059	0.098		е	5.46	BSC	0.215	5 BSC	
b	0.99	1.40	0.039	0.055		ØК	0.2	254	0.0	010	
b1	0.99	1.35	0.039	0.053		L	19.81	20.32	0.780	0.800	
b2	1.65	2.39	0.065	0.094		L1	3.71	4.29	0.146	0.169	
b3	1.65	2.34	0.065	0.092		ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035		Ø P1	-	6.98	-	0.275	
c1	0.38	0.84	0.015	0.033		Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3	R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4	S	5.51	BSC	0.217	' BSC	
D2	0.51	1.35	0.020	0.053			•		•		•

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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